

# Current Transducer HAIS 50..400-P and HAIS 50..100-TP

For the electronic measurement of currents: DC, AC, pulsed, mixed, with a galvanic isolation between the primary circuit (high power) and the secondary circuit (electronic circuit).









All Data are given with a  $R_1 = 10 \text{ k}\Omega$ 

## COMPLIANT 2002/95/EC

| Electrical data                                 |  |                           |                      |  |  |  |
|---|--|---------------------------|----------------------|--|--|--|
| Primary nominal current rms I <sub>PN</sub> (A) | Primary current,<br>measuring range<br>I <sub>PM</sub> (A) | Туре                      | RoHS since date code |  |  |  |
| 50  | ± 150  | HAIS 50-P, HAIS 50-TP1)   | 45231, 46272         |  |  |  |
| 100   | ± 300  | HAIS 100-P, HAIS 100-TP1) | 45231, 46012         |  |  |  |
| 150   | ± 450  | HAIS 150-P                | 46172                |  |  |  |
| 200   | ± 600  | HAIS 200-P                | 45231                |  |  |  |
| 400   | ± 600  | HAIS 400-P                | planned              |  |  |  |
| V 0   | itnut voltage (Analog)                                     | @ I V                     | ±(0.625.L/L ) \/     |  |  |  |

| <b>V</b> <sub>OUT</sub> | Output voltage (Analog) @ I <sub>P</sub>  |     | <b>V</b> <sub>REF</sub> ±(0.625- <b>I</b> | <sub>P</sub> /I <sub>PN</sub> ) V |
|-------------------------|---|-----|---|-----------------------------------|
|                         | $I_{P} = 0$                               |     | $V_{REF} \pm 0.025$                       | V                                 |
| $\mathbf{V}_{REF}$      | Reference voltage 2) - Output voltage     |     | $2.5 \pm 0.025$                           | V                                 |
|                         | V <sub>REF</sub> Output impedance         | typ | . 200                                     | $\Omega$                          |
|                         | <b>V</b> <sub>REF</sub> Load impedance    |     | ≥ 200                                     | kΩ                                |
| R,                      | Load resistance                           |     | ≥ 2                                       | $k\Omega$                         |
| R <sub>OUT</sub>        | Output internal resistance                |     | < 10                                      | $\Omega$                          |
| <b>C</b>                | Capacitive loading                        |     | < 1                                       | μF                                |
| <b>V</b> <sub>C</sub>   | Supply voltage (± 5 %)                    |     | 5   | V                                 |
| I <sub>c</sub>          | Current consumption @ $V_c = 5 \text{ V}$ |     | 22  | mΑ                                |

## Accuracy - Dynamic performance data

| X   | Accuracy $^{3)}$ @ $\mathbf{I}_{PN}$ , $\mathbf{T}_{A} = 25^{\circ}\text{C}$ | ≤ <b>±</b> 1  | % of I <sub>PN</sub>      |
|---|--|---------------|---------------------------|
| $\mathbf{e}_{\!\scriptscriptstyle \perp}$ | Linearity error 0 3 x I <sub>PN</sub>  | $\leq$ ± 0.5  | % of I <sub>PN</sub>      |
| TCV                                       | Temperature coefficient of $\mathbf{V}_{OE}$ @ $\mathbf{I}_{P} = 0$          | $\leq$ ± 0.3  | mV/K                      |
| TCV <sub>REF</sub>                        | Temperature coefficient of V <sub>REF</sub>                                  | $\leq$ ± 0.01 | %/K                       |
| $TCV_{OUT}/V_{REF}$                       | Temperature coefficient of $V_{OUT}/V_{REF} @ I_P = 0$                       | $\leq$ ± 0.2  | mV/K                      |
| TCV <sub>OUT</sub>                        | Temperature coefficient of <b>V</b> <sub>out</sub>                           | ≤±0.05% d     | of reading/K              |
| <b>V</b> <sub>OM</sub>                    | Magnetic offset voltage @ $I_p = 0$ ,  |               |                           |
|   | after an overload of 3 x I <sub>PN DC</sub>                                  | $< \pm 0.4$   | % of $I_{_{\mathrm{PN}}}$ |
| t <sub>ra</sub>                           | Reaction time @ 10 % of I <sub>PN</sub>                                      | < 3           | μs                        |
| t,  | Response time to 90 % of I <sub>PN</sub> step                                | < 5           | μs                        |
| di/dt                                     | di/dt accurately followed  | > 100         | A/µs                      |
| <b>V</b> <sub>no</sub>                    | Output voltage noise (DC10 kHz)  | < 15          | mVpp                      |
| -   | (DC 1 MHz)   | < 40          | mVpp                      |
| BW  | Frequency bandwidth (-3 dB) 4)   | DC 50         | kHz                       |
|   |  |               |                           |

Notes: 1) -TP version is equipped with a primary bus bar.

- 2) It is possible to overdrive V<sub>REF</sub> with an external reference voltage between 2 - 2.8 V providing its ability to sink or source approximately 2.5 mA.
- <sup>3)</sup> Excluding offset and hysteresis.
- <sup>4)</sup> Small signal only to avoid excessive heatings of the magnetic core.

## $I_{PN} = 50 ... 400 A$



## **Features**

- Hall effect measuring principle
- Galvanic isolation between primary and secondary circuit
- Isolation test voltage 2500V
- Low power consumption
- Single power supply +5V
- Fixed offset & gain
- Bus bar version available for 50A and 100A ratings.
- Isolated plastic case recognized according to UL94-V0.

## **Advantages**

- Small size and space saving
- Only one design for wide current ratings range
- High immunity to external interference.
- V<sub>REF.</sub> IN/OUT

## **Applications**

- AC variable speed drives
- Static converters for DC motor drives
- Battery supplied applications
- Uninterruptible Power Supplies (UPS)
- Switched Mode Power Supplies (SMPS)
- Power supplies for welding applications.

## **Application domain**

Industrial



## Current Transducer HAIS 50..400-P and HAIS 50..100-TP

| Gen                       | eral data   |   |            |              |  |
|---------------------------|---|---|------------|--------------|--|
| T <sub>A</sub>            | Ambient operating temperature                     |   | - 40 +     | . 85 °C      |  |
| $\mathbf{T}_{s}$          | Ambient storage temperature                       |   |            | - 40 + 85 °C |  |
| m                         | Mass (in brackets : TP version)                   |   | 20 (30)    | g            |  |
|                           | Standards   |   | EN 501     | 78: 1997     |  |
| Isola                     | ation characteristics                             |   |            |              |  |
| $V_{_{\mathrm{b}}}$       | Rated isolation voltage rms                       |   | 300        | V rms        |  |
|                           | with IEC 61010-1 standards and                    | following conditions  | s          |              |  |
|                           | - Single insulation                               |   |            |              |  |
|                           | <ul> <li>Over voltage category III</li> </ul>     |   |            |              |  |
|                           | - Pollution degree 2                              |   |            |              |  |
|                           | <ul> <li>Heterogeneous field</li> </ul>           |   |            |              |  |
| $V_{_{\rm b}}$            | Rated isolation voltage rms                       |   | 600        | V rms        |  |
|                           | with EN 50178 standards and fo                    | ollowing conditions   |            |              |  |
|                           | - Reinforced insulation                           |   |            |              |  |
|                           | - Over voltage category III                       |   |            |              |  |
|                           | - Pollution degree 2                              |   |            |              |  |
|                           | - Heterogeneous field                             | . =0.11 4 1   | 0.5        |              |  |
| V <sub>d</sub>            | Rms voltage for AC isolation tes                  |   | 2.5        | kV           |  |
| $\mathbf{V}_{\mathrm{e}}$ | Partial discharge extinction volta                | •   |            | 1.3.7        |  |
|                           |   | HAIS 50400-P  | >1         | kV           |  |
| ŵ                         | Impulse withstand voltage 1.2/F                   | HAIS 50100-TP   |            | kV<br>kV     |  |
| Ŷ <sub>w</sub><br>dCp     | Impulse withstand voltage 1.2/5 Creepage distance | υ μs  | 8<br>> 8   | m m          |  |
| dCp<br>dCl                | Clearance distance                                |   | > 0<br>> 8 | mm           |  |
| CTI                       | Comparative tracking index (Gro                   | oup I)  | > 600      | 111111       |  |
| CII                       | Comparative tracking index (Orc                   | λαρ I)  | > 000      |              |  |
|                           | If insulated cable is used for the                | primary circuit the   |            |              |  |
|                           |   | If insulated cable is used for the primary circuit, the voltage category could be improved with the following table : |            |              |  |
|                           | Cable insulation (primary)                        | Category  | ing table  | -            |  |
|                           | HAR 03  | 450V CAT III  |            |              |  |
|                           | HAR 05  | 550V CAT III  |            |              |  |
|                           | HAR 07  | 650V CAT III  |            |              |  |
|                           |   |   |            |              |  |

## Safety



This transducer must be used in electric/electronic equipment with respect to applicable standards and safety requirements in accordance with the following manufacturer's operating instructions.



Caution! Risk of electrical shock

When operating the transducer, certain parts of the module can carry hazardous voltage (eg. primary busbar, power supply).

Ignoring this warning can lead to injury and/or cause serious damage.

This transducer is a built-in device, whose conducting parts must be inaccessible after installation.

A protective housing or additional shield could be used.

Main supply must be able to be disconnected.

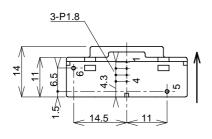


## **Dimensions HAIS 50..400-P and HAIS 50..100-TP** (in mm. 1 mm = 0.0394 inch)

## HAIS 50..400-P

# Front view 33 15 2-D1.0 4-0.25x0.45

## **Bottom view**



## Terminal Pin Identification

- 1...+5V
- 2...0V
- 3...OUTPUT
- 4...Vref. (IN/OUT)
- 5...Core Earth (\*)
- 6...NC.

## Recommended PCB hole

Pin 1-4: 0.7 ±0.1mm Pin 5-6: 1.5 ±0.1mm

Primary bus bar: 2.3 ±0.1mm

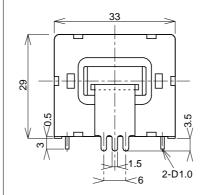
General tolerance: ±0.2mm

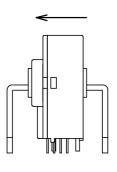
Unit: mm

## HAIS 50..100-TP

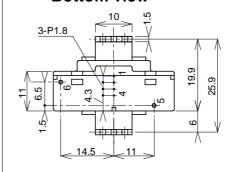
## Front view

## **Right view**

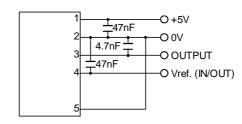




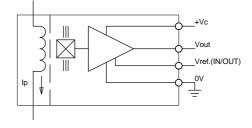
## **Bottom view**



## Required Connection Circuit



## Operation Principle



<sup>(\*)</sup> should be connected to 0V of Power Supply for better dv/dt immunity. Arrow indicates positive current direction.